

STC03DE220HV

Hybrid emitter switched bipolar transistor ESBT $^{\circledR}$ 2200 V - 3 A - 0.33 Ω

Features

Table 1. Features

V _{CS(ON)}	Ic	R _{CS(ON)}
1V	3A	0.33Ω

- Low equivalent on resistance
- Very fast-switch, up to 150 kHz
- Very low C_{ISS} driven by $R_G = 4.7 \Omega$

Applications

■ Aux SMPS for three phase mains

Description

The STC03DE220HV is manufactured in a hybrid structure, using dedicated high voltage Bipolar and low voltage MOSFET technologies, aimed to providing the best performance in ESBT topology. The STC03DE220HV is designed for use in aux flyback smps for any three phase application.

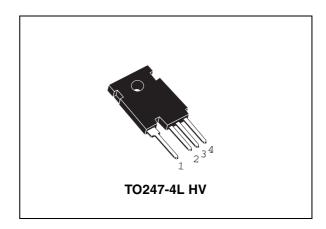


Figure 1. Internal schematic diagrams

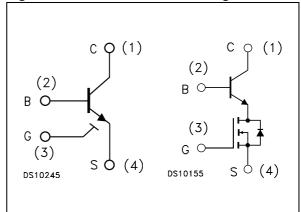


Table 2. Device summary

Order code	Marking	Package	Packaging
STC03DE220HV	STC03DE220HV C03DE220HV		Tube

Electrical ratings STC03DE220HV

1 Electrical ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CS(SS)}	Collector-source voltage (V _{BS} = V _{GS} =0)	2200	V
V _{BS(OS)}	Base-source voltage (I _C = 0, V _{GS} = 0)	30	V
V _{SB(OS)}	Source-base voltage ($I_C = 0$, $V_{GS} = 0$)	9	٧
V _{GS}	Gate-source voltage ±20		٧
I _C	Collector current	3	Α
I _{CM}	Collector peak current (t _P < 5 ms)	6	Α
I _B	Base current	3	Α
I _{BM}	Base peak current (t _P < 1 ms)	6	Α
P _{tot}	Total dissipation at T _c ≤25 °C 166		W
T _{stg}	Storage temperature -40 to 150		°C
TJ	Max. operating junction temperature	125	°C

Table 4. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	0.6	°C/W

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$

Table 5. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CS(SS)}	Collector-source current (V _{BS} =V _{GS} = 0)	V _{CS(SS)} = 2200 V			100	μA
I _{BS(OS)}	Base-source current (I _C =0, V _{GS} = 0)	V _{BS(OS)} = 30 V			10	μΑ
I _{SB(OS)}	Source-base current (I _C =0, V _{GS} = 0)	V _{SB(OS)} = 9 V			100	μΑ
I _{GS(OS)}	Gate-source leakage (V _{BS} = 0)	V _{GS} = ± 20 V			500	nA
V _{CS(ON)}	Collector-source ON voltage	$V_{GS} = 10 \text{ V } I_{C} = 1.5 \text{ A } I_{B} = 0.15 \text{ A}$ $V_{GS} = 10 \text{ V } I_{C} = 3 \text{ A } I_{B} = 0.6 \text{ A}$		0.2 0.25		V V
h _{FE}	DC current gain	V _{CS} = 1 V V _{GS} =10 V I _C =1.5 A V _{CS} = 1 V V _{GS} =10 V I _C =3 A		15 10		
V _{BS(ON)}	Base-source ON voltage	$V_{GS} = 10 \text{ V } I_C = 1.5 \text{ A } I_B = 0.15 \text{ A}$ $V_{GS} = 10 \text{ V } I_C = 3 \text{ A } I_B = 0.6 \text{ A}$		0.82		V V
V _{GS(th)}	Gate threshold voltage	$V_{BS} = V_{GS}$ $I_B = 250 \mu A$	1.5	2.2	3	V
C _{iss}	Input capacitance (V _{GS} = V _{CB} = 0)	V _{CS} = 25 V f = 1 MHz		750		pF
Q _{GS(tot)}	Gate-source Charge (V _{CB} = 0)	$V_{CS} = 15 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_{C} = 1.8 \text{ A}$		12.5		nC
t _s	INDUCTIVE LOAD Storage time Fall time	$V_{GS} = 10 \text{ V}$ $R_G = 47 \Omega$ $V_{Clamp} = 1760 \text{ V}$ $t_p = 4 \mu s$ $I_C = 1.5 \text{ A}$ $I_B = 0.3 \text{ A}$		1040 20		ns ns
V _{CS(dyn)}	Collector-source dynamic voltage (500 ns)	$\begin{split} &V_{CC} = V_{Clamp} = 400 \ V \\ &V_{GS} = 10 \ V &I_{C} = 1.5 \ A \\ &I_{B} = 0.3 \ A &R_{G} = 47 \ \Omega \\ &t_{peak} = 500 \ ns &I_{Bpeak} = 3 \ A \end{split}$		7.6		V
V _{CS(dyn)}	Collector-source dynamic voltage (1 µs)	$\begin{split} & \text{V}_{\text{CC}} = \text{V}_{\text{Clamp}} = 400 \text{ V} \\ & \text{V}_{\text{GS}} = 10 \text{ V} \\ & \text{I}_{\text{C}} = 1.5 \text{ A} \\ & \text{I}_{\text{B}} = 0.3 \text{ A} \\ & \text{t}_{\text{peak}} = 500 \text{ ns} \\ \end{split}$		5.8		V
V _{CSW}	Maximum collector- source voltage switched without snubber	$R_G = 47 \Omega$ $h_{FE} = 5$ $I_C = 3 A$	2200			V

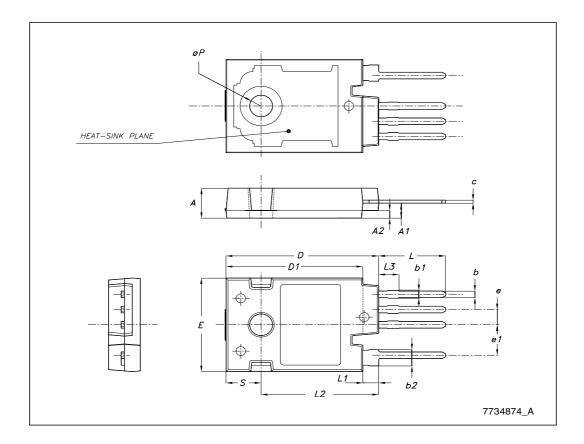
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3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO247-4L HV mechanical data

DIM.		mm.	
	MIN.	TYP	MAX.
Α	4.85		5.15
A1	2.20	2.50	2.60
A2		1.27	
b	0.95	1.10	1.30
b1	1.10		1.50
b2	2.50		2.90
С	0.40		0.80
D	23.85	24	24.15
D1		21.50	
E	15.45	15.60	15.75
е		2.54	
e1		5.08	
L	10.20		10.80
L1	2.20	2.50	2.80
L2		18.50	
L3		3	
øΡ	3.55		3.65
S		5.50	



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Revision history STC03DE220HV

4 Revision history

Table 6. Document revision history

Date	Revision	Changes	
27-Nov-2006	1	First release.	
19-May-2008	2	Document status promoted from preliminary data to datasheet.	

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